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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete if Known	
				Application Number	10/022,722
				Filing Date	December 20, 2001
				First Named Inventor	Glen Hush
				Art Unit	2818
				Examiner Name	H. Hoang
Sheet	1	of	1	Attorney Docket Number	M4065.0481/P481

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
HL	AA	5,761,112	06/02/1998	Murray et al.	
HL	AB	US 2001/0012214 A1	09/09/2001	Akita et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)				
HL	BC	WO 01/45108 A1	06/21/2001			
HL	BD	EP 0 274 828	07/20/1988			

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OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²

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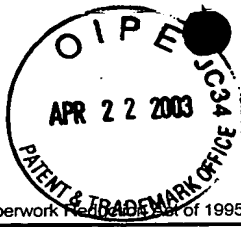
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U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	AA	6,469,364	10/2002	Kozicki	} duplicate (see paper # 3)
	AB	2002/0168820 App.	11/2002	Kozicki	
WV	AC	2002/0072188 App	6/2002	Gilton	
	AD	2002/0123169 App	9/2002	Moore et al.	
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	AG	3,743,847	7/1973	Boland	
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	AO	4,847,674	7/1989	Sliwa et al.	
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				Filing Date	December 20, 2001
				First Named Inventor	Glen Hush
				Art Unit	2818
				Examiner Name	H. Hoang
Sheet	2	of	4	Attorney Docket Number	M4065.0481/P481

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	AV1	2003/0027416 APP	2/6/2003	Moore	
	AW1	2003/0001229 APP	1/2/2003	Moore et al.	
	AX1	2002/0106849 APP	8/8/2002	Moore	
	AY1	2002/0127886 APP	9/12/2002	Moore et al.	
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	BB1	6,072,716	6/2000	Jacobson et al.	
	BC1	5,272,359	12/93	Nagasubramanian et al.	
	BD1	4,671,618	6/87	Wu et al.	
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	BF1	2003/0035314	02/20/03	Kozicki	
	BG1	2003/0035315	02/20/03	Kozicki	
✓	BH1	6,473,332	04/04/01	Ignatiev et al.	



PTO/SB/08A (10-01)

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Sheet	3	of	4	Attorney Docket Number	M4065.0481/P481

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		Country Code ² -Number ³ -Kind Code ⁴ (if known)				
HU	BA	JP 56126916	10/1981	Akira et al.		
	BB					

Examiner Signature	Huan Hoang	Date Considered	11/1/03
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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	10/193,529
				Filing Date	July 10, 2002
				First Named Inventor	Kristy A. Campbell
				Group Art Unit	2714
				Examiner Name	H. Weiss
				Attorney Docket Number	M4065.0695/P695
Sheet	4	of	4		

PRIOR ART – NON PATENT LITERATURE DOCUMENTS			T ²
Examiner Initials	Cite No.¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
CA		Axon Technologies Corporation, TECHNOLOGY DESCRIPTION: <u>Programmable Metalization Cell(PMC)</u> , pp. 1-6 (Pre-May 2000).	
CB		Helbert et al., <u>Intralayer hybrid resist process with submicron capability</u> , SPIE Vol. 333 SUBMICRON LITHOGRAPHY, pp. 24-29 (1982).	
CC		Hill, DISSERTATION: <u>Materials characterization of Silver Chalcogenide Programmable Metalization Cells</u> , Arizona State University, pp. Title page-114 (UMI Company, May 1999).	
CD		Hirose et al., <u>High Speed Memory Behavior and Reliability of an Amorphous As₂S₃ Film Doped Ag</u> , PHYS. STAT. SOL. (a) 61, pp. 87-90 (1980).	
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CJ		Kozicki et al., <u>Nanoscale effects in devices based on chalcogenide solid solutions</u> , Superlattices and Microstructures, 27, 485-488 (2000).	
CK		Kozicki et al., <u>Nanoscale phase separation in Ag-Ge-Se glasses</u> , Microelectronic Engineering, vol. 63/1-3, 155-159 (2002).	
CL		M.N. Kozicki and M. Mitkova, <u>Silver incorporation in thin films of selenium rich Ge-Se glasses</u> , Proceedings of the XIX International Congress on Glass, Society for Glass Technology, 226-227 (2001).	
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CP			
CQ			

Examiner Signature	Huan Hoang	Date Considered	11/1/03
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